

1. Features

- Typical 1dB bandwidth of 9.2 MHz
- High attenuation
- Single Ended Operation
- Dual In-line Package (DIP)

RoHS Compliant

Tested by SGS Testing Korea

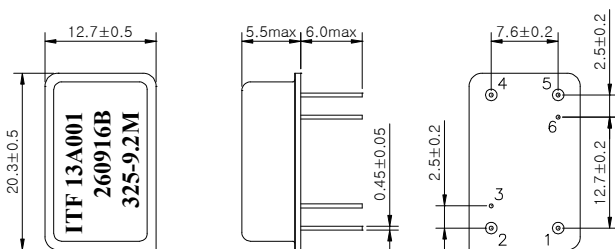
2. Electrical Specifications

Source and Load Impedance = 50Ω

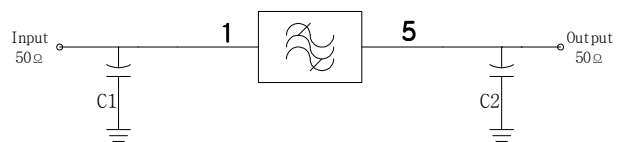
Room Temperature : +25°C		Minimum	Typical	Maximum
Center Frequency (fo)	MHz	324.84	325.0	325.16
Insertion Loss	dB	-	27.0	29.0
1dB Bandwidth	MHz	9.15	9.25	-
3dB Bandwidth	MHz	-	9.56	-
45dB Bandwidth	MHz	-	10.96	11.1
Amplitude Ripple (Fo±4.5075MHz)	dB	-	0.6	1.4
Group Delay Variation (Fo±4.5075MHz)	nsec	-	180	300
Absolute Delay	usec	-	2.24	2.3
Ultimate Rejection	dB	45	50	-
Temperature Coefficient of Frequency	ppm/°C	-	-18	-
Substrate Material	-		112-LT	

Input POWER : +10dBm

D2012 Package Dimension



Matching Schematic



C1 = C2 = 30pF

Pin Configuration

Input	1	Ground	2, 4
Output	5	Others	Ground

Dimensions shown are nominal in millimeters

Base : Fe(SPCC), Au plating over Ni plated
Cap : Cu & Cr Alloy, Ni Plated
Termination : Kovar, Au Plated

3. Typical Performance (at +25°C)

